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## WHAT IS CLAIMED IS:

1. A semiconductor light-emitting device comprising:

a semiconductor light-emitting device chip including a chip substrate and a stack formed of semiconductor layers stacked on a surface of said chip substrate: and

a mount member having a mount surface, wherein

said semiconductor light-emitting device chip is connected to the mount surface of said mount member with said stack facing said mount surface, and

said mount member includes a material higher in thermal expansion coefficient than a material for said chip substrate.

2. A semiconductor light-emitting device comprising:

a semiconductor light-emitting device chip including a chip substrate and a stack formed of semiconductor layers stacked on a surface of said chip substrate; and

a mount member having a mount surface, wherein

said semiconductor light-emitting device chip is connected to the mount surface of said mount member with said stack facing said mount surface, and

said mount surface is curved to protrude and said semiconductor light-emitting device chip is curved along and connected to said mount surface.

3. The semiconductor light-emitting device according to claim 1, wherein

said chip substrate includes nitride-based compound semiconductor and said stack includes nitride-based compound semiconductor.

 ${\bf 4.} \quad {\bf The \ semiconductor \ light-emitting \ device \ according \ to \ claim \ 3,}$  wherein

said mount member includes at least one of iron and copper.

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- $5. \quad \text{The semiconductor light-emitting device according to claim 1,} \\$  wherein
- said mount surface and said stack are connected by solder and said solder includes at least one selected from the group consisting of In, Sn, Pb and Au.